

BAS21VD High-voltage switching diodes 1 August 2013

**Product data sheet** 

## 1. General description

Triple high-voltage switching diodes, encapsulated in a SOT457 (SC-74/TSOP6) small Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- High switching speed: t<sub>rr</sub> ≤ 50 ns
- Low capacitance: C<sub>d</sub> ≤ 5 pF
- Reverse voltage: V<sub>R</sub> ≤ 200 V
- AEC-Q101 qualified
- Repetitive peak reverse voltage: V<sub>RRM</sub> ≤ 250 V
- Repetitive peak forward current: I<sub>FRM</sub> ≤ 1 A
- Small SMD plastic package

## 3. Applications

- · High-voltage switching in surface-mounted circuits
- Automotive
- Communication

## 4. Quick reference data

Table 1. Qu	ick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode							
I <sub>F</sub>	forward current	pulsed; $t_p \le 300 \ \mu s$ ; $\delta \le 0.02$	[1]	-	-	200	mA
V <sub>R</sub>	reverse voltage			-	-	200	V
Per diode							
I <sub>R</sub>	reverse current	$V_R$ = 200 V; $T_{amb}$ = 25 °C; pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$		-	25	100	nA
t <sub>rr</sub>	reverse recovery time	I <sub>F</sub> = 30 mA; I <sub>R</sub> = 30 mA; I <sub>R(meas)</sub> = 3 mA; R <sub>L</sub> = 100 Ω; T <sub>amb</sub> = 25 °C		-	16	50	ns

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





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## 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)		6 5 4
2	K2	cathode (diode 2)		
3	K3	cathode (diode 3)		
4	A3	anode (diode 3)	TSOP6 (SOT457)	
5	A2	anode (diode 2)		1 2 3 006aab241
6	A1	anode (diode 1)		000880241

# 6. Ordering information

Table 3.         Ordering information					
Type number	Package				
	Name	Description	Version		
BAS21VD	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457		

## 7. Marking

Table 4. Marking codes	
Type number	Marking code
BAS21VD	B5

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
Per diode	·					,
V <sub>RRM</sub>	repetitive peak reverse voltage			-	250	V
V <sub>R</sub>	reverse voltage			-	200	V
I <sub>F</sub>	forward current	pulsed; $t_p \le 300 \ \mu s$ ; $\delta \le 0.02$	[1]	-	200	mA
I <sub>FRM</sub>	repetitive peak forward current	t <sub>p</sub> ≤ 1 ms; δ ≤ 25 %		-	1	А
I <sub>FSM</sub>	non-repetitive peak forward	$t_p$ = 10 µs; $T_{j(init)}$ = 25 °C; square wave		-	16	А
current		$t_p$ = 100 µs; $T_{j(init)}$ = 25 °C; square wave		-	8	А
		$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; square wave		-	2	А

#### High-voltage switching diodes

Symbol	Parameter	Conditions		Min	Max	Unit
Per device;	one diode loaded					
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
			[2]	-	295	mW
T <sub>stg</sub>	storage temperature			-65	150	°C
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

## 9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device; on	e diode loaded						,
R <sub>th(j-a)</sub>	thermal resistance	in free air	[1]	-	-	500	K/W
	from junction to ambient		[2]	-	-	425	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[3]	-	-	140	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

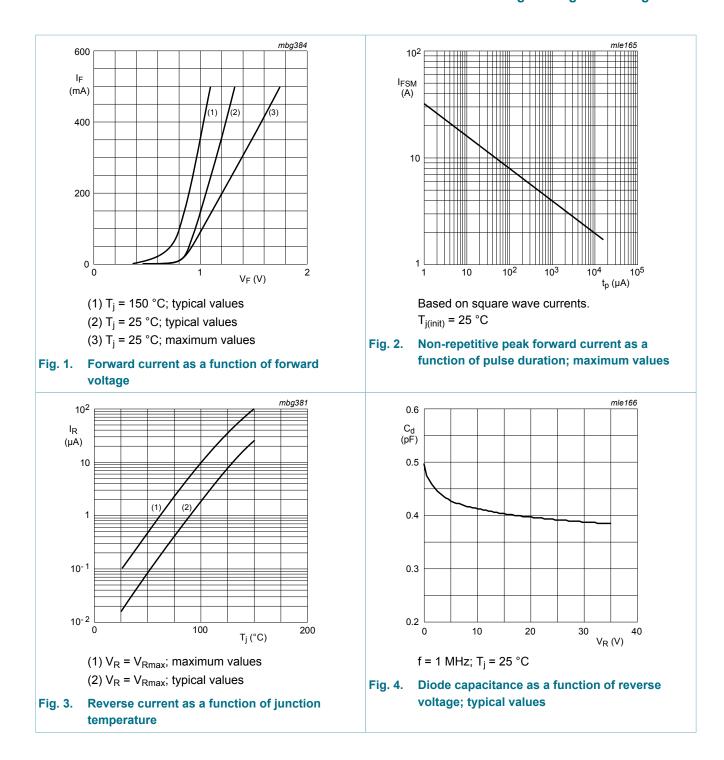
[3] Soldering point of cathode tab.

## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per diode		· · · ·	· ·			
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 100 mA; T <sub>amb</sub> = 25 °C	-	-	1	V
		I <sub>F</sub> = 200 mA; T <sub>amb</sub> = 25 °C	-	-	1.25	V
I <sub>R</sub> reverse current	$V_{R} = 200 \text{ V; pulsed; } t_{p} \le 300  \mu\text{s;}$ $\delta \le 0.02 \text{ ; } T_{amb} = 25 ^{\circ}\text{C}$	-	25	100	nA	
		V <sub>R</sub> = 200 V; T <sub>j</sub> = 150 °C	-	-	100	μA
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	0.6	5	pF
t <sub>rr</sub>	reverse recovery time	$I_F$ = 30 mA; $I_R$ = 30 mA; $T_{amb}$ = 25 °C; $R_L$ = 100 Ω; $I_{R(meas)}$ = 3 mA	-	16	50	ns

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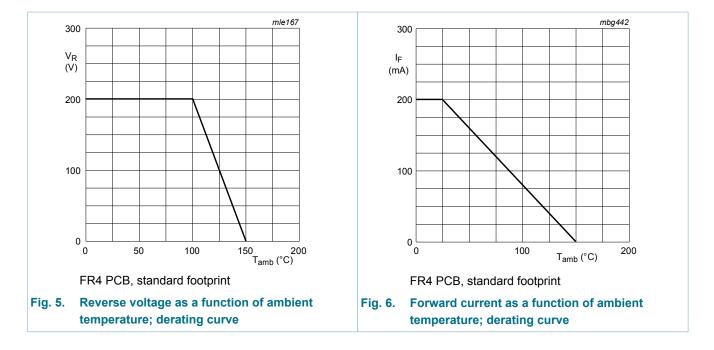
## High-voltage switching diodes



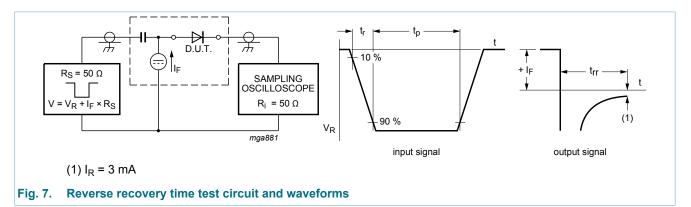
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### High-voltage switching diodes



## 11. Test information

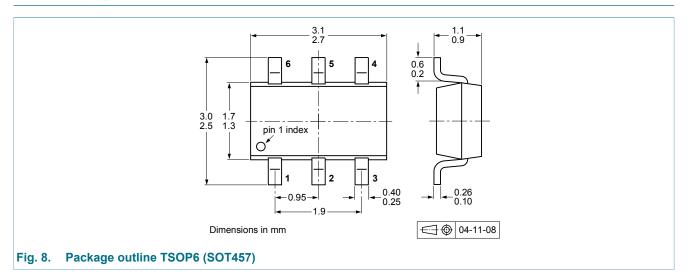


### **11.1 Quality information**

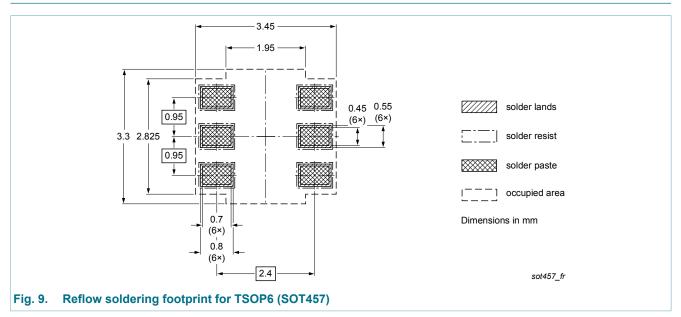
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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### 12. Package outline



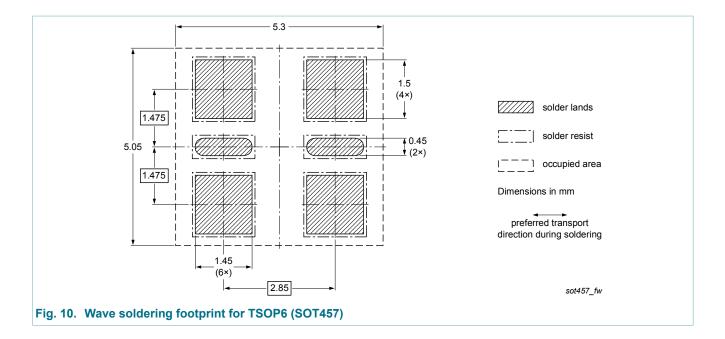
## 13. Soldering



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#### High-voltage switching diodes



# 14. Revision history

Table 8. Revision hi	story					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BAS21VD v.3	20130801	Product data sheet	-	BAS21VD v.2		
Modifications:	<ul> <li>Table 7. Characteristics: parameter unit of V<sub>F</sub> corrected</li> <li>Packing information: removed</li> <li>Legal information: updated</li> </ul>					
BAS21VD v.2	20110629	Product data sheet	-	BAS21VD v.1		
BAS21VD v.1	20030703	Product data sheet	-	-		

#### High-voltage switching diodes

### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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